

# PTVA120501EA

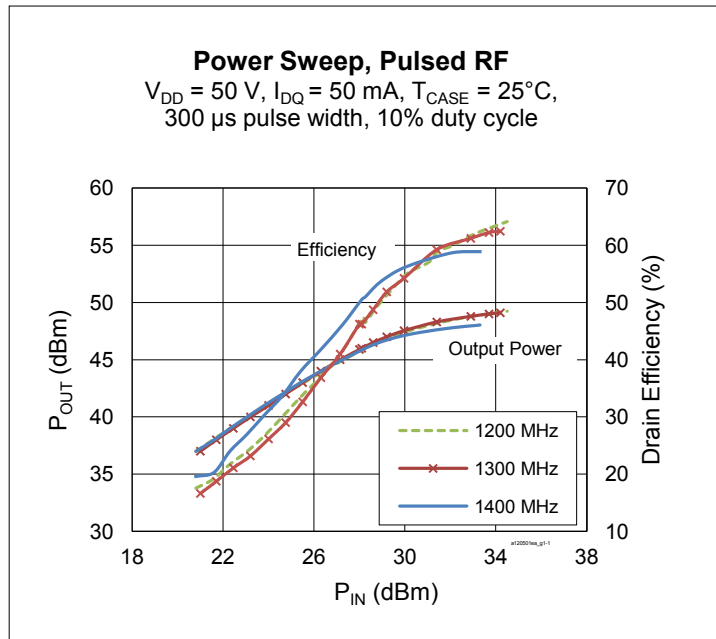
## Thermally-Enhanced High Power RF LDMOS FET 50 W, 50 V, 1200 – 1400 MHz

### Description

The PTVA120501EA LDMOS FET is designed for use in power amplifier applications in the 1200 to 1400 MHz frequency band. Features include high gain and thermally-enhanced package with bolt-down flange. Manufactured with an advanced LDMOS process, this device provides excellent thermal performance and superior reliability.



PTVA120501EA  
Package H-36265-2



### Features

- Broadband input matching
- High gain and efficiency
- Typical Pulsed CW performance, 1200 – 1400MHz, 50 V, 300  $\mu\text{s}$  pulse width, 10 % duty cycle, class AB
  - Output power at  $P_{1dB} = 54\text{ W}$
  - Efficiency = 55%
  - Gain = 16 dB
- Integrated ESD protection
- Low thermal resistance
- Pb-free and RoHS compliant
- Capable of withstanding a 10:1 load mismatch (all phase angles) at 50 W peak under RF pulse, 300  $\mu\text{s}$ , 10% duty cycle.

### RF Characteristics

#### Pulsed RF Performance (tested in the test fixture)

$V_{DD} = 50\text{ V}$ ,  $I_{DQ} = 50\text{ mA}$ ,  $P_{OUT} = 50\text{ W}$ ,  $f_1 = 1200\text{ MHz}$ ,  $f_2 = 1300\text{ MHz}$ ,  $f_3 = 1400\text{ MHz}$ , 300  $\mu\text{s}$  pulse width, 10 % duty cycle

| Characteristic   | Symbol   | Min  | Typ | Max | Unit |
|------------------|----------|------|-----|-----|------|
| Gain             | $G_{ps}$ | 16.5 | 17  | —   | dB   |
| Drain Efficiency | $\eta_D$ | 46   | 50  | —   | %    |
| Return Loss      | IRL      | —    | -10 | -7  | dB   |

All published data at  $T_{CASE} = 25^\circ\text{C}$  unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!



## RF Characteristics

**Typical RF Performance** (not subject to production test, verified by design/characterization in the test fixture)

$V_{DD} = 50\text{ V}$ ,  $I_{DQ} = 50\text{ mA}$ , Input signal ( $t_r = 7\text{ ns}$ ,  $t_f = 8\text{ ns}$ ), 300  $\mu\text{s}$  pulse width, 10% duty cycle, class AB test

| Mode of Operation | f (MHz) | IRL (dB) | P <sub>1dB</sub> |         |                      | P <sub>3dB</sub> |         |                      | Max P <sub>droop</sub> (pulse) dB @ 50 W | t <sub>r</sub> (ns) @ 50 W* | t <sub>f</sub> (ns) @ 50 W* |
|-------------------|---------|----------|------------------|---------|----------------------|------------------|---------|----------------------|------------------------------------------|-----------------------------|-----------------------------|
|                   |         |          | Gain (dB)        | Eff (%) | P <sub>OUT</sub> (W) | Gain (dB)        | Eff (%) | P <sub>OUT</sub> (W) |                                          |                             |                             |
| Pulsed RF         | 1200    | -8       | 16               | 56      | 60                   | 14               | 58      | 78                   | 0.20                                     | 5                           | <2                          |
| Pulsed RF         | 1300    | -10      | 16               | 57      | 60                   | 14               | 58      | 78                   | 0.20                                     | 5                           | <2                          |
| Pulsed RF         | 1400    | -8       | 16               | 55      | 54                   | 14               | 57      | 57                   | 0.15                                     | 5                           | <2                          |

\* Note =  $t_r$  and  $t_f$  are defined as  $\Delta$  between input and output rise and fall times

**Typical RF Performance** (not subject to production test, verified by design/characterization in the test fixture)

$V_{DD} = 50\text{ V}$ ,  $I_{DQ} = 50\text{ mA}$ , 30 ms pulse width, 33% duty cycle, class AB test

| Mode of Operation | f (MHz) | P <sub>1dB</sub> |         |                      | P <sub>3dB</sub> |         |                      | P <sub>droop</sub> (pulse) dB @ 50 W |
|-------------------|---------|------------------|---------|----------------------|------------------|---------|----------------------|--------------------------------------|
|                   |         | Gain (dB)        | Eff (%) | P <sub>OUT</sub> (W) | Gain (dB)        | Eff (%) | P <sub>OUT</sub> (W) |                                      |
| Pulsed RF         | 1200    | 16               | 57      | 57                   | 14               | 59      | 75                   | 0.3                                  |
| Pulsed RF         | 1300    | 16               | 56      | 55                   | 14               | 58      | 75                   | 0.3                                  |
| Pulsed RF         | 1400    | 16               | 49      | 50                   | 14               | 50      | 55                   | 0.2                                  |

## DC Characteristics

| Characteristic                 | Conditions                                       | Symbol        | Min | Typ | Max | Unit          |
|--------------------------------|--------------------------------------------------|---------------|-----|-----|-----|---------------|
| Drain-Source Breakdown Voltage | $V_{GS} = 0\text{ V}$ , $I_{DS} = 10\text{ mA}$  | $V_{(BR)DSS}$ | 105 | —   | —   | V             |
| Drain Leakage Current          | $V_{DS} = 50\text{ V}$ , $V_{GS} = 0\text{ V}$   | $I_{DSS}$     | —   | —   | 1   | $\mu\text{A}$ |
|                                | $V_{DS} = 105\text{ V}$ , $V_{GS} = 0\text{ V}$  | $I_{DSS}$     | —   | —   | 10  | $\mu\text{A}$ |
| On-State Resistance            | $V_{GS} = 10\text{ V}$ , $V_{DS} = 0.1\text{ V}$ | $R_{DS(on)}$  | —   | 0.4 | —   | $\Omega$      |
| Operating Gate Voltage         | $V_{DS} = 50\text{ V}$ , $I_{DQ} = 50\text{ mA}$ | $V_{GS}$      | 3.0 | 3.5 | 4.0 | V             |
| Gate Leakage Current           | $V_{GS} = 10\text{ V}$ , $V_{DS} = 0\text{ V}$   | $I_{GSS}$     | —   | —   | 1   | $\mu\text{A}$ |

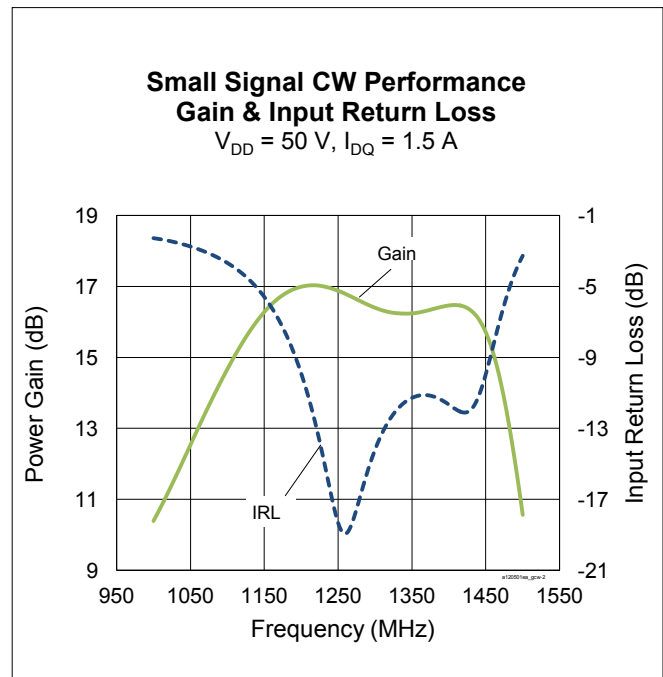
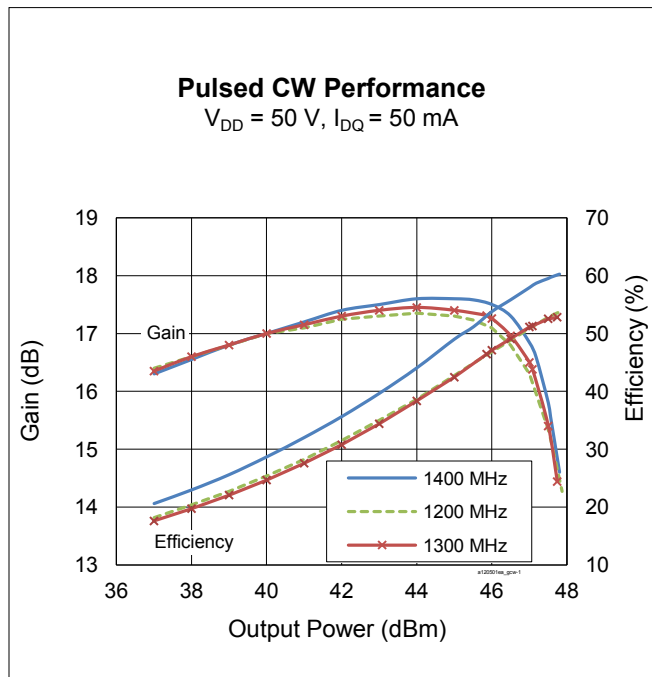
## Maximum Ratings

| Parameter                                                       | Symbol          | Value       | Unit |
|-----------------------------------------------------------------|-----------------|-------------|------|
| Drain-Source Voltage                                            | $V_{DSS}$       | 105         | V    |
| Gate-Source Voltage                                             | $V_{GS}$        | -6 to +12   | V    |
| Operating Voltage                                               | $V_{DD}$        | 0 to +55    | V    |
| Junction Temperature                                            | $T_J$           | 225         | °C   |
| Storage Temperature Range                                       | $T_{STG}$       | -65 to +150 | °C   |
| Thermal Resistance ( $T_{CASE} = 70^{\circ}\text{C}$ , 50 W CW) | $R_{\theta JC}$ | 1.37        | °C/W |

## Ordering Information

| Type and Version   | Order Code         | Package Description  | Shipping             |
|--------------------|--------------------|----------------------|----------------------|
| PTVA120501EA V1 R0 | PTVA120501EA-V1-R0 | H-36265-2, bolt-down | Tape & Reel, 50 pcs  |
| PTVA120501EA V1 R2 | PTVA120501EA-V1-R2 | H-36265-2, bolt-down | Tape & Reel, 250 pcs |

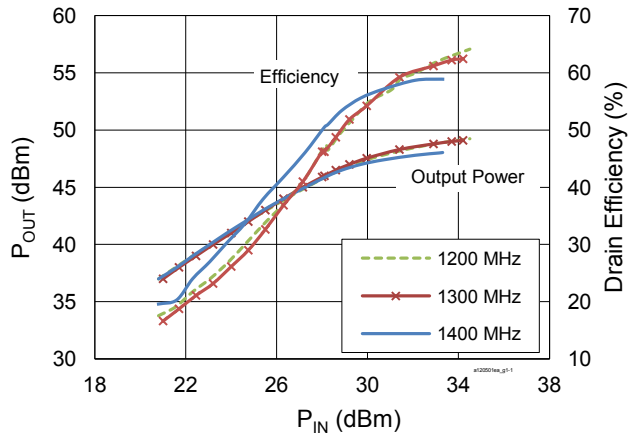
## Typical Performance (data taken in a production test fixture)



# Typical Performance (cont.)

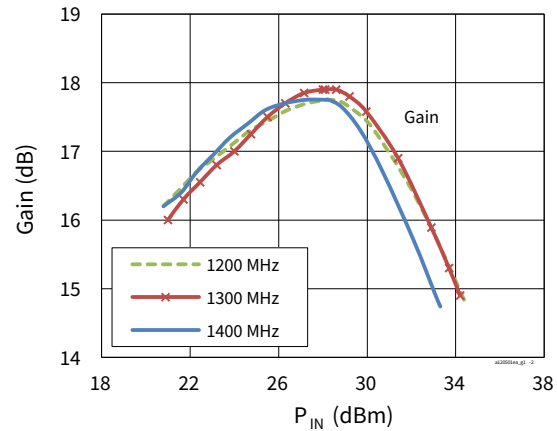
## Power Sweep, Pulsed RF

$V_{DD} = 50\text{ V}$ ,  $I_{DQ} = 50\text{ mA}$ ,  $T_{CASE} = 25^\circ\text{C}$ ,  
300  $\mu\text{s}$  pulse width, 10% duty cycle



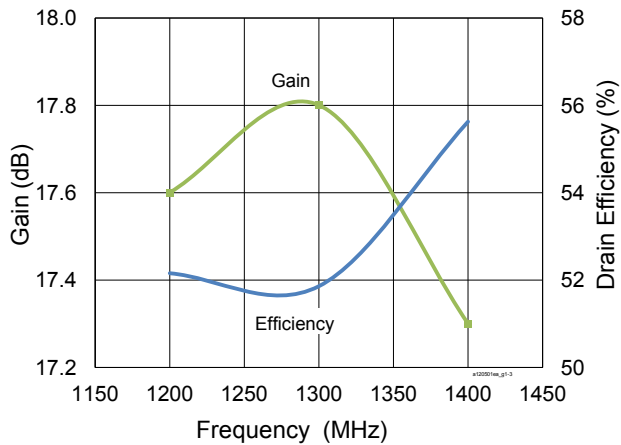
## Power Sweep, Pulsed RF

$V_{DD} = 50\text{ V}$ ,  $I_{DQ} = 50\text{ mA}$ ,  $T_{CASE} = 25^\circ\text{C}$ ,  
300  $\mu\text{s}$  pulse width, 10% duty cycle



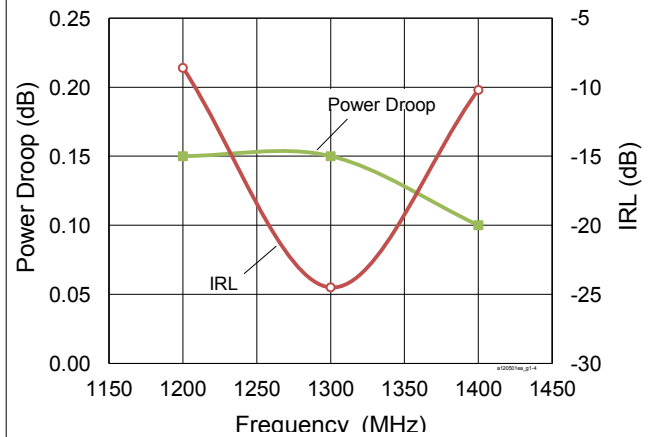
## Power Sweep, Pulsed RF

$V_{DD} = 50\text{ V}$ ,  $I_{DQ} = 50\text{ mA}$ ,  $P_{OUT} = 50\text{ W}$ ,  
300  $\mu\text{s}$  pulse width, 10% duty cycle

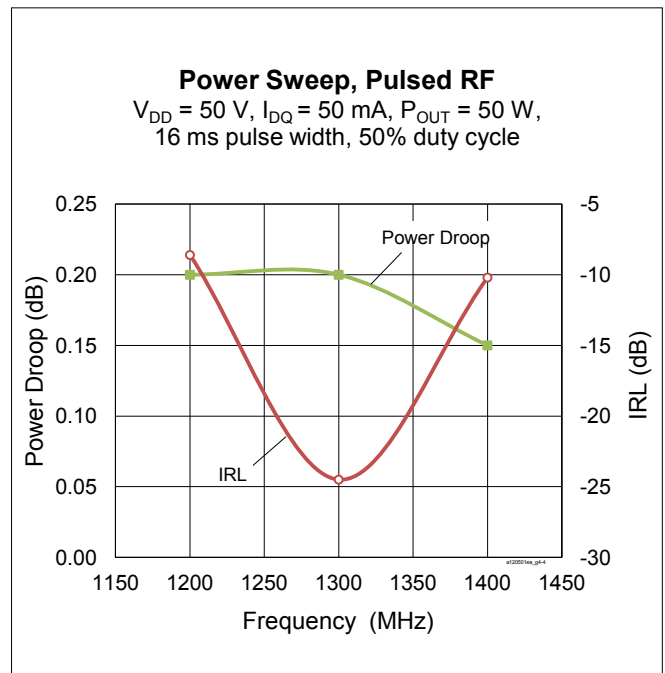
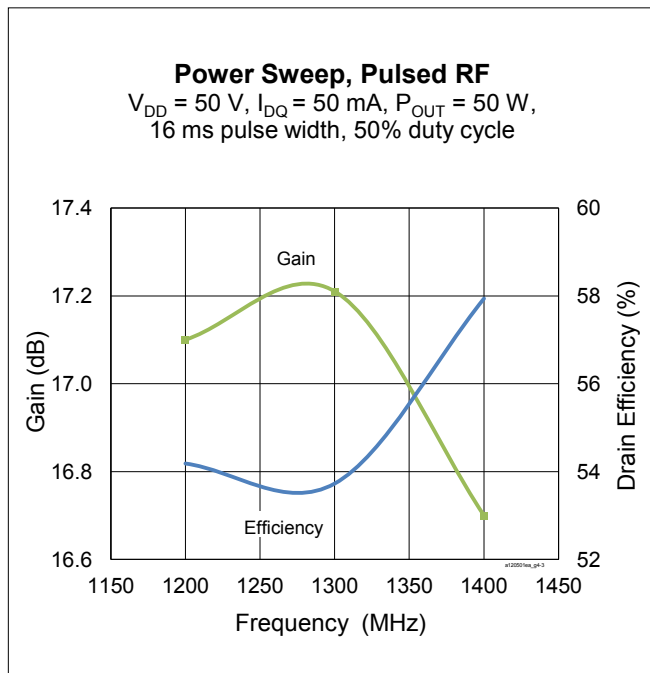
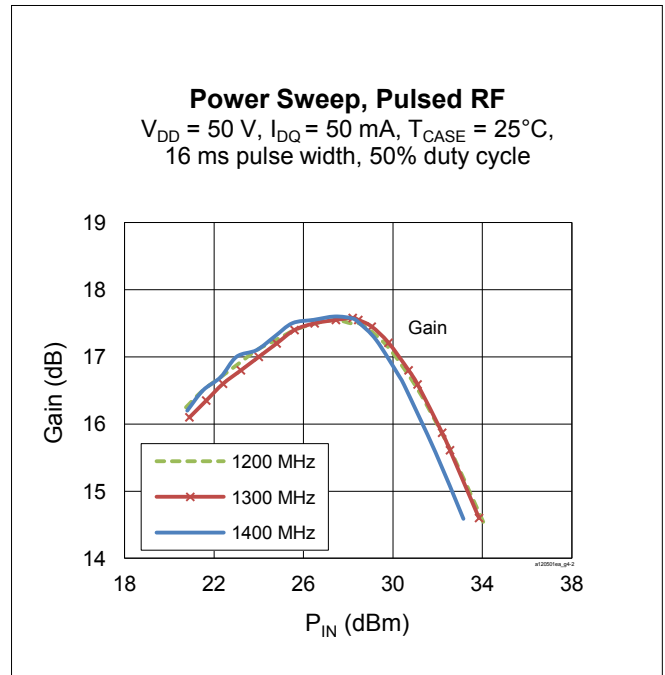
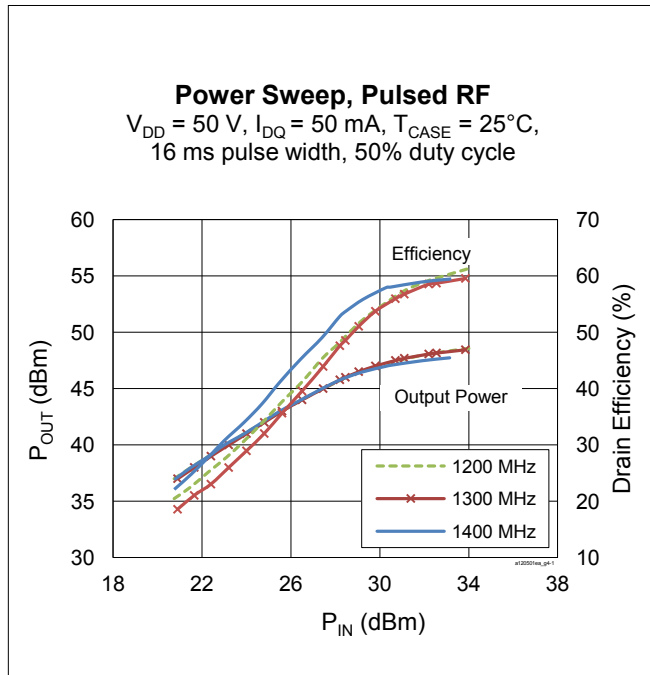


## Power Sweep, Pulsed RF

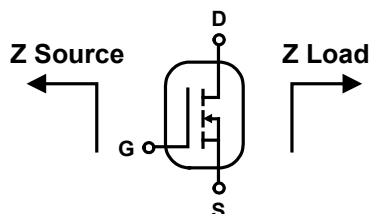
$V_{DD} = 50\text{ V}$ ,  $I_{DQ} = 50\text{ mA}$ ,  $P_{OUT} = 50\text{ W}$ ,  
300  $\mu\text{s}$  pulse width, 10% duty cycle



# Typical Performance (cont.)



## Broadband Circuit Impedance



| Freq<br>[MHz] | Z Source $\Omega$ |       | Z Load $\Omega$ |      |
|---------------|-------------------|-------|-----------------|------|
|               | R                 | jX    | R               | jX   |
| 1200          | 8.07              | -2.13 | 3.66            | 4.97 |
| 1300          | 5.13              | -0.95 | 3.90            | 4.56 |
| 1400          | 5.64              | 2.24  | 3.25            | 5.36 |

## Load Pull Performance

**Load Pull at Max  $P_{OUT}$  Point** – 16  $\mu$ s pulse width, 10% duty cycle, class AB,  $V_{DD} = 50$  V, 50 mA

| Freq<br>[MHz] | $Z_L$<br>[ $\Omega$ ] | $P_{IN}$<br>[dBm] | $P_{OUT}$<br>[dBm] | $P_{OUT}$<br>[W] | $P_G$<br>[dB] | PAE Eff<br>[%] | $Z_{OUT}$<br>[ $\Omega$ ] |
|---------------|-----------------------|-------------------|--------------------|------------------|---------------|----------------|---------------------------|
| 1200          | $3.04 - j2.16$        | 30.68             | 47.30              | 53.70            | 16.62         | 45.56          | $3.19 - j1.55$            |

**Load Pull at Max  $G_T$  Point** – 16  $\mu$ s pulse width, 10% duty cycle, class AB,  $V_{DD} = 50$  V, 50 mA

| Freq<br>[MHz] | $Z_L$<br>[ $\Omega$ ] | $P_{IN}$<br>[dBm] | $P_{OUT}$<br>[dBm] | $P_{OUT}$<br>[W] | $P_G$<br>[dB] | PAE Eff<br>[%] | $Z_{OUT}$<br>[ $\Omega$ ] |
|---------------|-----------------------|-------------------|--------------------|------------------|---------------|----------------|---------------------------|
| 1200          | $3.04 - j2.16$        | 27.50             | 46.10              | 40.74            | 18.60         | 57.50          | $2.88 - j4.11$            |

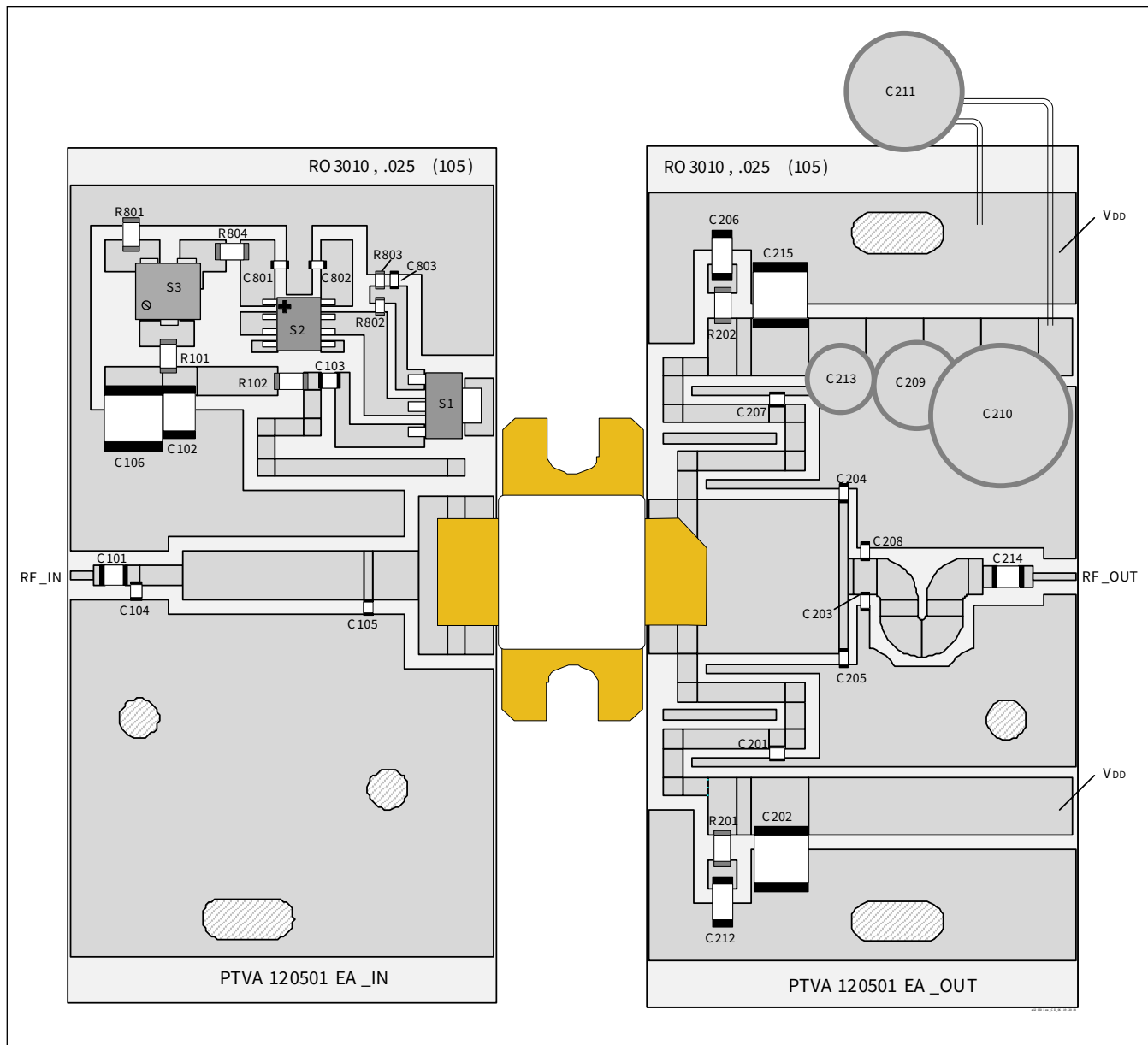
**Load Pull at Max Efficiency Point** – 16  $\mu$ s pulse width, 10% duty cycle, class AB,  $V_{DD} = 50$  V, 50 mA

| Freq<br>[MHz] | $Z_L$<br>[ $\Omega$ ] | $P_{IN}$<br>[dBm] | $P_{OUT}$<br>[dBm] | $P_{OUT}$<br>[W] | $P_G$<br>[dB] | PAE Eff<br>[%] | $Z_{OUT}$<br>[ $\Omega$ ] |
|---------------|-----------------------|-------------------|--------------------|------------------|---------------|----------------|---------------------------|
| 1200          | $3.04 - j2.16$        | 27.55             | 46.15              | 41.21            | 18.60         | 57.20          | $2.88 - j4.06$            |

**Z Optimum** – 16  $\mu$ s pulse width, 10% duty cycle, class AB,  $V_{DD} = 50$  V, 50 mA

| Freq<br>[MHz] | $Z_L$<br>[ $\Omega$ ] | $P_{IN}$<br>[dBm] | $P_{OUT}$<br>[dBm] | $P_{OUT}$<br>[W] | $P_G$<br>[dB] | PAE Eff<br>[%] | $Z_{OUT}$<br>[ $\Omega$ ] |
|---------------|-----------------------|-------------------|--------------------|------------------|---------------|----------------|---------------------------|
| 1200          | $3.04 - j2.16$        | 28.70             | 46.57              | 45.39            | 17.87         | 50.46          | $2.92 - j3.12$            |

## Reference Circuit , 1200 – 1400 MHz



Reference circuit assembly diagram (not to scale)

## Reference Circuit (cont.)

### Reference Circuit Assembly

|                       |                                                                                                 |
|-----------------------|-------------------------------------------------------------------------------------------------|
| DUT                   | PTVA120501EA                                                                                    |
| Test Fixture Part No. | LTN/PTVA120501EA V1                                                                             |
| PCB                   | Rogers 6006, 0.635 mm [0.025"] thick, 2 oz. copper, $\epsilon_r = 6.15$ , $f = 1200 - 1400$ MHz |

### Components Information

| Component        | Description                | Suggested Manufacturer             | P/N                 |
|------------------|----------------------------|------------------------------------|---------------------|
| <b>Input</b>     |                            |                                    |                     |
| C101             | Capacitor, 39 pF           | ATC                                | ATC100B390KW500XB   |
| C102             | Capacitor, 1 $\mu$ F       | TDK Corporation                    | C4532X7R2A105M230KA |
| C103             | Capacitor, 33 pF           | ATC                                | ATC100A330JW150XB   |
| C104             | Capacitor, 2.7 pF          | ATC                                | ATC800A2R7BT        |
| C105             | Capacitor, 10 pF           | ATC                                | ATC800A100JT        |
| C106             | Capacitor, 10 $\mu$ F      | TDK Corporation                    | C5750X5R1H106K230KA |
| C801, C802, C803 | Capacitor, 1000 pF         | Panasonic Electronic Components    | ECJ-1VB1H102K       |
| R101             | Resistor, 1000 $\Omega$    | Panasonic Electronic Components    | ERJ-8GEYJ102V       |
| R102             | Resistor, 10 $\Omega$      | Panasonic Electronic Components    | ERJ-8GEYJ100V       |
| R801             | Resistor, 2000 $\Omega$    | Panasonic Electronic Components    | ERJ-8GEYJ202V       |
| R802             | Resistor, 1200 $\Omega$    | Panasonic Electronic Components    | ERJ-3GEYJ122V       |
| R803             | Resistor, 1300 $\Omega$    | Panasonic Electronic Components    | ERJ-3GEYJ132V       |
| R804             | Resistor, 100 $\Omega$     | Panasonic Electronic Components    | ERJ-8GEYJ100V       |
| S1               | Transistor                 | Infineon Technologies              | BCP56               |
| S2               | Voltage Regulator          | Texas Instruments                  | LM78L05ACM          |
| S3               | Potentiometer, 2k $\Omega$ | Bourns Inc.                        | 3224W-1-202E        |
| <b>Output</b>    |                            |                                    |                     |
| C201, C207       | Capacitor, 33 pF           | ATC                                | ATC100A330JW150XB   |
| C202, C215       | Capacitor, 10 $\mu$ F      | TDK Corporation                    | C5750X5R1H106K230KA |
| C203, C208       | Capacitor, 3.9 pF          | ATC                                | ATC800A3R9BT        |
| C204, C205       | Capacitor, 6.8 pF          | ATC                                | ATC800A6R8BT        |
| C206, C212       | Capacitor, 1 $\mu$ F       | TDK Corporation                    | C4532X7R2A105M230KA |
| C209             | Capacitor, 22 $\mu$ F      | Cornell Dubilier Electronics (CDE) | SEK220M100ST        |
| C210             | Capacitor, 100 $\mu$ F     | Cornell Dubilier Electronics (CDE) | SK101M100ST         |
| C211             | Capacitor, 6800 $\mu$ F    | Cornell Dubilier Electronics (CDE) | ECO-S2AP682EA       |
| C213             | Capacitor, 10 $\mu$ F      | Cornell Dubilier Electronics (CDE) | SEK100M100ST        |
| C214             | Capacitor, 39 pF           | ATC                                | ATC100B390KW500XB   |
| R201, R202       | Resistor, 5600 $\Omega$    | Panasonic Electronic Components    | ERJ-8RQJ5R6V        |

## Package Outline Specifications

### Package H-36265-2

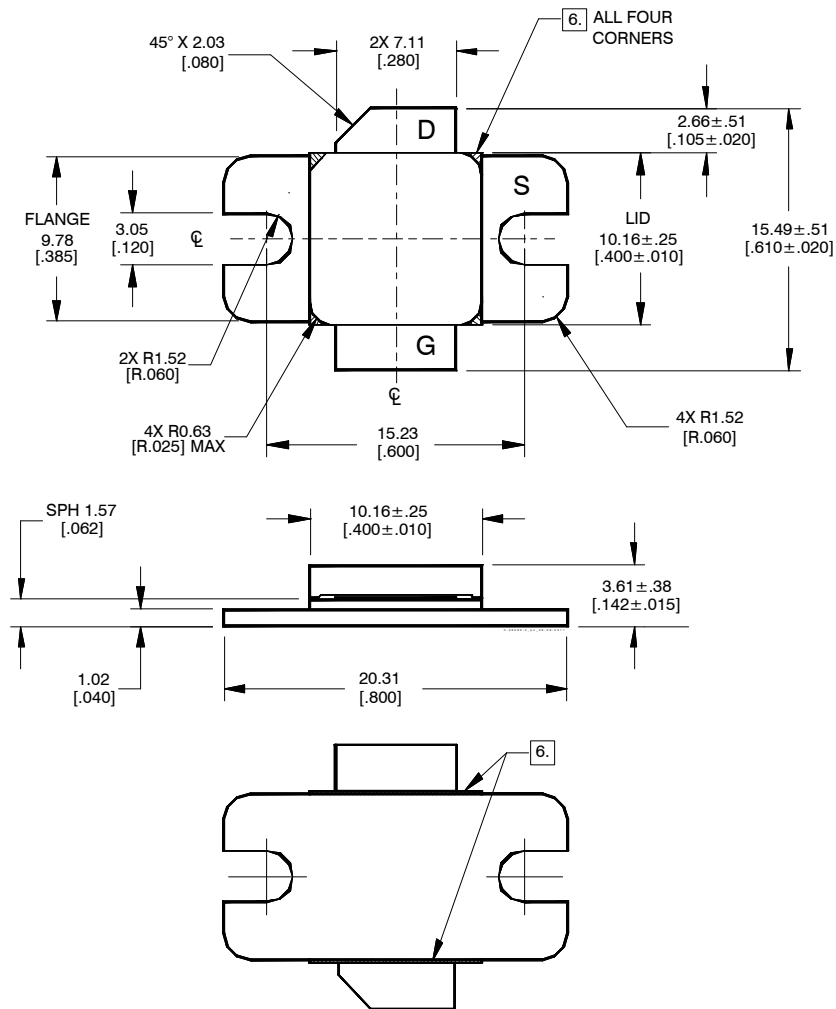


Diagram Notes—unless otherwise specified:

1. Interpret dimensions and tolerances per ASME Y14.5M-1994.
2. Primary dimensions are mm. Alternate dimensions are inches.
3. All tolerances  $\pm 0.127$  [0.005] unless specified otherwise.
4. Pins: D – drain; G – gate; S – source
5. Lead thickness:  $0.10 + 0.051/-0.025$  mm [ $0.004 + 0.002/-0.001$  inch].
6. Exposed metal plane on top and bottom of ceramic insulator.
7. Gold plating thickness:  $1.14 \pm 0.38$  micron [ $45 \pm 15$  microinch].

## Notes & Disclaimer

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